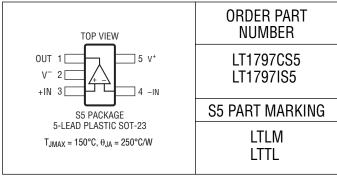
ABSOLUTE MAXIMUM RATINGS

(Note 1)
Total Supply Voltage (V+ to V ⁻)
Input Differential Voltage 12.6\
Input Current ±10mA
Output Short-Circuit Duration (Note 2) Continuous
Operating Temperature Range
(Note 3) –40°C to 85°C
Specified Temperature Range40°C to 85°C
Junction Temperature 150°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, OV; $V_S = 5V$, OV, $V_{CM} = V_{OUT} = half supply, pulse power tested, unless otherwise specified. (Note 3)$

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	$\begin{array}{l} 0^{\circ}C \leq T_{A} \leq 70^{\circ}C \\ -40^{\circ}C \leq T_{A} \leq 85^{\circ}C \end{array}$	•		1	1.5 2.5 3.0	mV mV mV
	Input Offset Voltage Drift (Note 4)		•		5	20	μV/°C
I _B	Input Bias Current	$V_{CM} = V^-$ $V_{CM} = V^+$	•	-300	-150 50	100	nA nA
	Input Bias Current Drift		•		0.1		nA/°C
I _{OS}	Input Offset Current	$V_{CM} = V^-$ $V_{CM} = V^+$	•		10 10	25 25	nA nA
	Input Noise Voltage	0.1Hz to 10Hz			1.5		μV _{P-P}
e _n	Input Noise Voltage Density	f = 10kHz			20		nV/√Hz
i _n	Input Noise Current Density	f = 10kHz $f = 10kHz, V_{CM} = V_{CC} - 0.3V$			0.23 0.15		pA/√Hz pA/√Hz
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = 0V to V _S - 1.3V		200	330 100		kΩ MΩ
C _{IN}	Input Capacitance				4		pF
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0V \text{ to } V_S - 1.3V$ $V_S = 5V, V_{CM} = 0V \text{ to } 5V$ $V_S = 3V, V_{CM} = 0V \text{ to } 3V$	•	82 64 60	96 72 68		dB dB dB
	Input Voltage Range		•	0		Vs	V
A _{VOL}	Large-Signal Voltage Gain	$V_S = 3V$, $V_0 = 0.5V$ to 2.5V, $R_L = 10k$	•	200 150	1000		V/mV V/mV
		$V_S = 5V$, $V_0 = 0.5V$ to 4.5V, $R_L = 10k$	•	400 300	1000		V/mV V/mV

ELECTRICAL CHARACTERISTICS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V, $V_{CM} = V_{OUT} = half supply, pulse power tested, unless otherwise specified. (Note 3)$

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
PSRR	Power Supply Rejection Ratio	$V_S = 2.7V$ to 12V, $V_{CM} = V_0 = 1V$	•	80	90		dB
	Minimum Supply Voltage		•		2.5	2.7	V
V_{OL}	Output Voltage Swing LOW	No Load, Input Overdrive = 30mV	•		8	30	mV
		I _{SINK} = 5mA	•		80	160	mV
		I _{SINK} = 10mA	•		150	250	mV
V_{OH}	Output Voltage Swing HIGH	No Load, Input Overdrive = 30mV	•		$V_{S} - 0.05$		V
		I _{SOURCE} = 5mA	•	$V_{\rm S} - 0.30$			V
		I _{SOURCE} = 10mA	•	$V_{S} - 0.39$	$V_{S} - 0.3$		V
I_{SC}	Short-Circuit Current	$V_S = 5V$		25	45		mA
		$V_S = 3V$		15	25		mA
I _S	Supply Current				1.1	1.5	mA
· ·			•			2.0	mA
GBW	Gain Bandwidth Product (Note 5)	f = 100kHz		6.0	10		MHz
		$0^{\circ}\text{C} \leq \text{T}_{A} \leq 70^{\circ}\text{C}$	•	5.0			MHz
		-40 °C $\leq T_A \leq 85$ °C	•	4.5			MHz
SR	Slew Rate (Note 5)	$A_V = -1$		1.3	2.25		V/µs
		$0^{\circ}C \leq T_{A} \leq 70^{\circ}C$	•	1.1			V/µs
		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$	•	1.0			V/µs
t _r	Output Rise Time	10% to 90%, 0.1V Step, R _L = 10k			55		ns
t _f	Output Fall Time	10% to 90%, 0.1V Step, R _L = 10k			55		ns
t _S	Settling Time	$V_S = 5V$, $\Delta V_{OUT} = 2V$ to 0.1%, $A_V = -1$			1.6		μs
THD	Distortion	$V_S = 3V$, $V_{OUT} = 1.8V_{P-P}$, $A_V = 1$, $R_L = 10k$, $f = 1kHz$			0.001		%
FPBW	Full-Power Bandwidth (Note 6)	$V_{OUT} = 2V_{P-P}$			360		kHz

The ullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 5V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, pulse power tested unless otherwise specified. (Note 3)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
$\overline{V_{0S}}$	Input Offset Voltage				1	1.5	mV
		$0^{\circ}\text{C} \leq \text{T}_{A} \leq 70^{\circ}\text{C}$	•			2.5	mV
		$-40^{\circ}\text{C} \le \text{T}_{A} \le 85^{\circ}\text{C}$	•			3.0	mV
	Input Offset Voltage Drift (Note 4)		•		5	20	μV/°C
I _B	Input Bias Current	$V_{CM} = V^-$	•	-300	-150		nA
		$V_{CM} = V^+$	•		50	100	nA
	Input Bias Current Drift		•		0.1		nA/°C
I _{OS}	Input Offset Current	V _{CM} = V ⁻	•		10	25	nA
		$V_{CM} = V^+$	•		10	25	nA
	Input Noise Voltage	0.1Hz to 10Hz			1		μV _{P-P}
e _n	Input Noise Voltage Density	f = 10kHz			20		nV/√Hz
in	Input Noise Current Density	f = 10kHz			0.23		pA/√Hz
		$f = 10kHz, V_{CM} = 4.7V$			0.15		pA/√Hz
R _{IN}	Input Resistance	Differential		200	330		kΩ
		Common Mode, $V_{CM} = -5V$ to 3.7V			100		MΩ
C _{IN}	Input Capacitance				4		pF
<u></u>	Input Voltage Range		•	- 5		5	V

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ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 5V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, pulse power tested unless otherwise specified. (Note 3)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
CMRR	Common Mode Rejection Ratio	$V_{CM} = -5V$ to 3.7V $V_{CM} = -5V$ to 5V	•	78 66	96 76		dB dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = \pm 4V, R_L = 10k$	•	400 300	1000		V/mV V/mV
V _{OL}	Output Voltage Swing LOW	No Load, Input Overdrive = 30mV I _{SINK} = 5mA I _{SINK} = 10mA	•		-4.99 -4.92 -4.85	-4.97 -4.87 -4.79	V V V
V _{OH}	Output Voltage Swing HIGH	No Load, Input Overdrive = 30mV I _{SOURCE} = 5mA I _{SOURCE} = 10mA	•	4.84 4.70 4.61	4.95 4.80 4.70		V V V
I _{SC}	Short-Circuit Current (Note 2)	Short to GND		30	50		mA
PSRR	Power Supply Rejection Ratio	$V_S = \pm 1.35 V \text{ to } \pm 6 V$	•	80	90		dB
I _S	Supply Current		•		1.40	2.25 3.00	mA mA
GBW	Gain Bandwidth Product	$ f = 100kHz \\ 0^{\circ}C \le T_{A} \le 70^{\circ}C \\ -40^{\circ}C \le T_{A} \le 85^{\circ}C $	•	6.5 5.5 5.0	11		MHz MHz MHz
SR	Slew Rate	$A_V=-1,~R_L=\infty,~V_0=\pm 4V,~Measured~at~V_0=\pm 2V$ $0^{\circ}C\leq T_A\leq 70^{\circ}C$ $-40^{\circ}C\leq T_A\leq 85^{\circ}C$	•	1.50 1.25 1.10	2.50		V/μs V/μs V/μs
t _r	Output Rise Time	10% to 90%, 0.1V Step, R _L = 10k			55		ns
t _f	Output Fall Time	10% to 90%, 0.1V Step, R _L = 10k			55		ns
t _S	Settling Time	$\Delta V_{OUT} = 4V \text{ to } 0.1\%, A_V = 1$			2.6		μs
FPBW	Full-Power Bandwidth (Note 6)	$V_{OUT} = 8V_{P-P}$			100		kHz

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum.

Note 3: The LT1797C is guaranteed to meet 0° C to 70° C specifications and is designed, characterized and expected to meet the extended temperature limits, but is not tested at -40° C and 85° C. The LT1797I is guaranteed to meet specified performance from -40° C to 85° C.

Note 4: This parameter is not 100% tested.

Note 5: $V_S = 3V$ limit guaranteed by correlation to 5V tests.

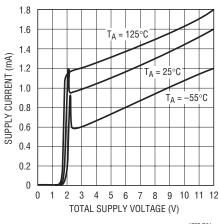
Note 6: Full-power bandwidth is calculated from the slew rate:

 $FPBW = SR/2\pi V_P$

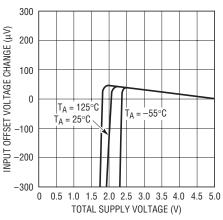
TECHNOLOGY TECHNOLOGY

TYPICAL PERFORMANCE CHARACTERISTICS

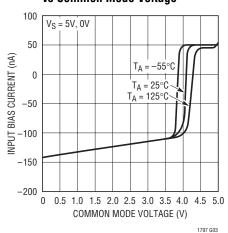
Supply Current vs Supply Voltage



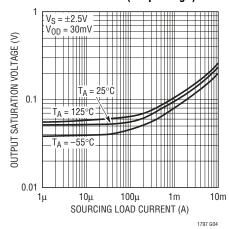
Minimum Supply Voltage



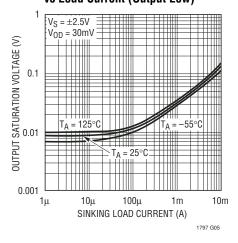
Input Bias Current vs Common Mode Voltage



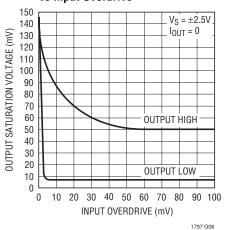
Output Saturation Voltage vs Load Current (Output High)



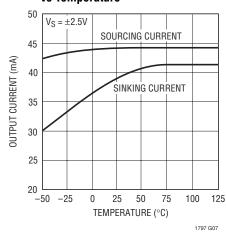
Output Saturation Voltage vs Load Current (Output Low)



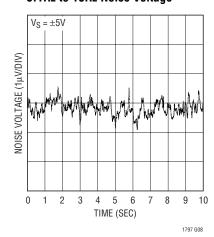
Output Saturation Voltage vs Input Overdrive



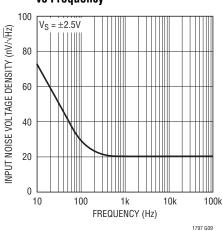
Output Short-Circuit Current vs Temperature



0.1Hz to 10Hz Noise Voltage



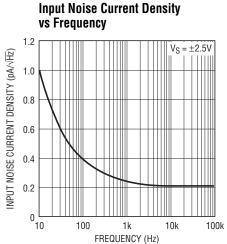
Input Noise Voltage Density vs Frequency

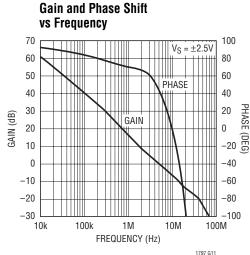


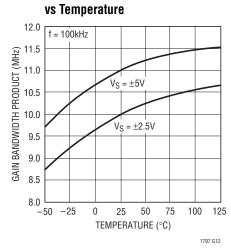
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TYPICAL PERFORMANCE CHARACTERISTICS

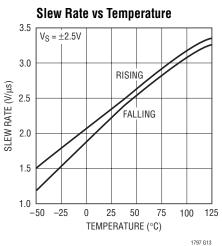
1797 G10

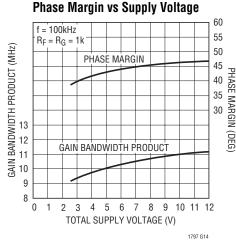




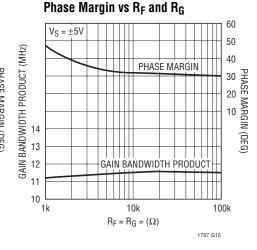


Gain Bandwidth Product

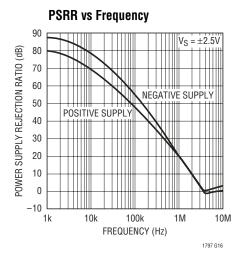


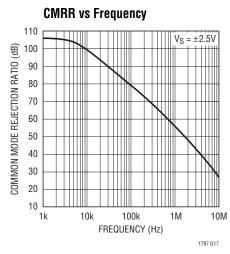


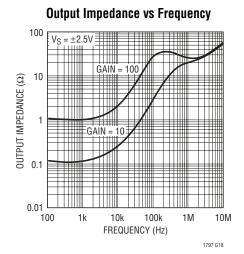
Gain Bandwidth Product and



Gain Bandwidth Product and



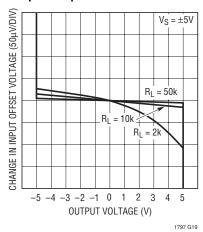




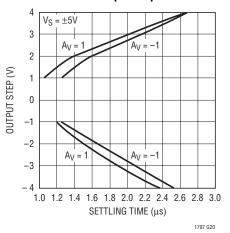
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TYPICAL PERFORMANCE CHARACTERISTICS

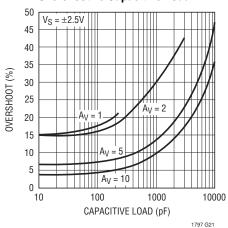
Open-Loop Gain



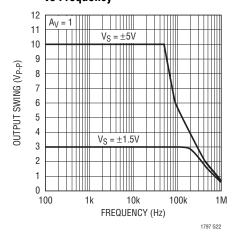
Settling Time to 0.1% vs Output Step



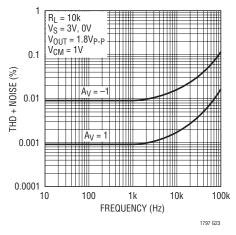
Capacitive Load Handling Overshoot vs Capacitive Load



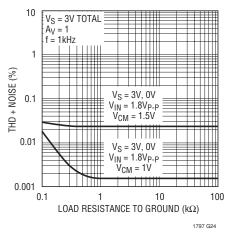
Undistorted Output Swing vs Frequency



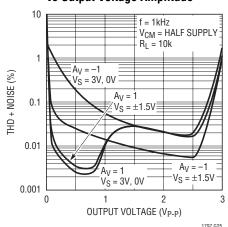
Total Harmonic Distortion + Noise vs Frequency



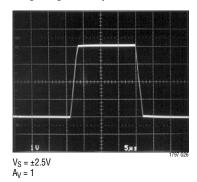
Total Harmonic Distortion + Noise vs Load Resistance



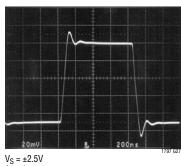
Total Harmonic Distortion + Noise vs Output Voltage Amplitude



Large-Signal Response



Small-Signal Response



 $R_L = 10k$

APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1797 should be bypassed with a small capacitor (about $0.1\mu F$) within an inch of the pin. When driving heavy loads an additional $4.7\mu F$ electrolytic capacitor should be used. When using split supplies the same is true for the negative supply pin.

Inputs

The LT1797 is fully functional for an input signal range from the negative supply to the positive supply. Figure 1 shows a simplified schematic of the amplifier. The input stage consists of two differential amplifiers, a PNP stage Q3/Q4 and an NPN stage Q1/Q2 that are active over different ranges of input common mode voltage. The PNP differential pair is active for input common mode voltages V_{CM} between the negative supply to approximately 1.3V below the positive supply. As V_{CM} moves closer toward the positive supply, the transistor QB1 will steer the tail current I1 to the current mirror Q5/Q6, activating the NPN differential pair and the PNP pair becomes inactive for the rest of the input common mode range up to the positive supply.

The input offset voltage and the input bias current are dependent on which input stage is active. The input offset voltage is trimmed on a single 5V supply with the common mode at 1/2 supply and is typically 1mV with the PNP stage active. The input offset of the NPN stage is untrimmed and is typically 1.5mV. The input bias current polarity depends on the input common mode voltage. When the PNP differential pair is active, the input bias currents flow out of the input pins. They flow in the opposite direction when the NPN input stage is active. The offset error due to the input bias currents can be minimized by equalizing the noninverting and inverting source impedance.

The input stage of the LT1797 incorporates phase reversal protection to prevent false outputs from occurring when the inputs are driven up to 5V beyond the rails. Protective resistors are included in the input leads so that current does not become excessive when the inputs are forced beyond the supplies or when a large differential signal is applied.

Output

The output is configured with a pair of complementary common emitter stages Q19/Q20, which enable the output to swing from rail-to-rail. The output voltage swing of the LT1797 is affected by input overdrive as shown in the Typical Performance Characteristics. When monitoring input voltages within 50mV of V⁺ or within 8mV of V⁻, some gain should be taken to keep the output from clipping. The output of the LT1797 can deliver large load currents; the short-circuit current limit is typically 50mA at ±5V. Take care to keep the junction temperature of the IC below the absolute maximum rating of 150°C. The output of the amplifier has reverse biased diodes to each supply. If the output is forced beyond either supply, unlimited current will flow through these diodes.

The LT1797 can drive capacitive loads up to 200pF on a single 5V supply in a unity gain configuration. When there is a need to drive larger capacitive loads, a resistor of a couple hundred ohms should be connected between the output and the capacitive load. The feedback should still be taken from the output so that the resistor isolates the capacitive load to ensure stability. The low input bias current of the LT1797 makes it possible to use high value feedback resistors to set the gain. However, care must be taken to insure that the pole formed by the feedback resistors and the total capacitance at the inverting input does not degrade stability.

APPLICATIONS INFORMATION

Distortion

There are two main contributors to distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current and distortion caused by nonlinear common mode rejection. If the op amp is operating in the inverting mode, there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 1.3V of V+), the CMRR is very good,

typically 96dB. When the LT1797 switches between input stages there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion, but has no effect on the input stage transition distortion. For lowest distortion the LT1797 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and $(V^+ - 1.3V)$. See the Typical Performance Characteristic curves.

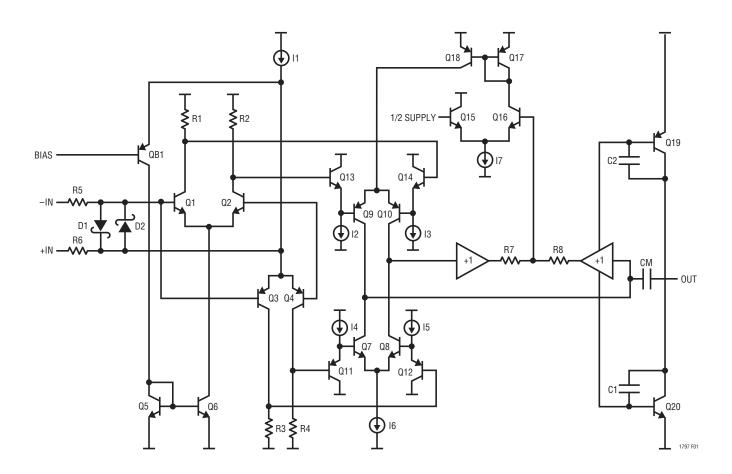
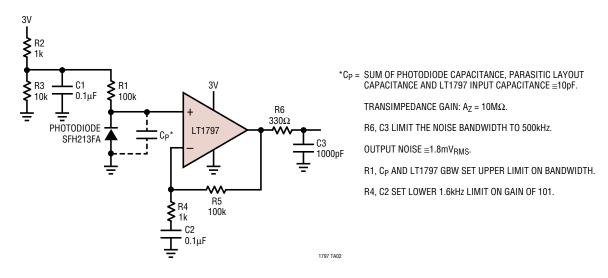


Figure 1. Simplified Schematic

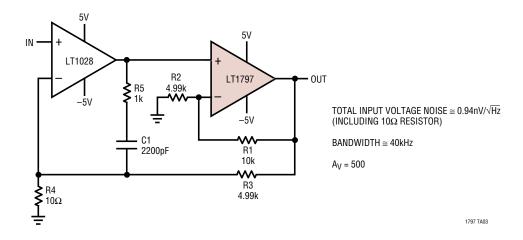


TYPICAL APPLICATIONS

Single Supply Hi-Gain 80kHz Photodiode Amplifier



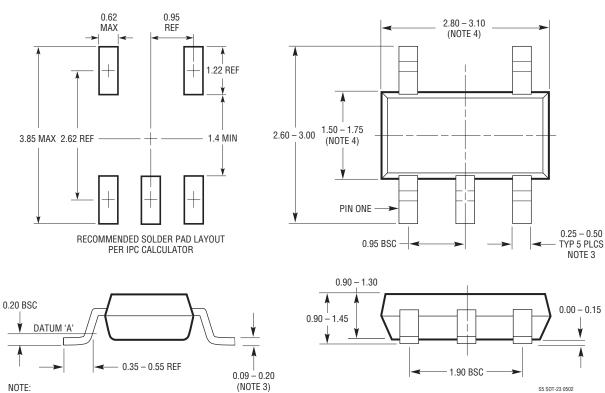
Ultra-Low Noise, ±5V Supply, Rail-to-Rail Output Amplifier



PACKAGE DESCRIPTION

S5 Package 5-Lead Plastic SOT-23

(Reference LTC DWG # 05-08-1633)



- 1. DIMENSIONS ARE IN MILLIMETERS
- 2. DRAWING NOT TO SCALE
- 3. DIMENSIONS ARE INCLUSIVE OF PLATING
- 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
- 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
- 6. PACKAGE EIAJ REFERENCE IS SC-74A (EIAJ)

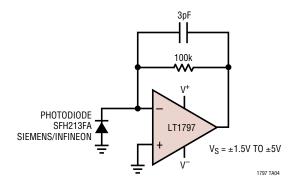
ATTENTION: ORIGINAL SOT23-5L PACKAGE.

MOST SOT23-5L PRODUCTS CONVERTED TO THIN SOT23 PACKAGE, DRAWING # 05-08-1635 AFTER APPROXIMATELY APRIL 2001 SHIP DATE

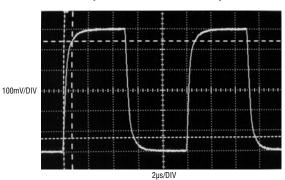


TYPICAL APPLICATION

1MHz Photodiode Transimpedance Amplifier



Response of Photodiode Amplifier



Rise Time vs Supply Voltage (600mV Output Step)

Supply Voltage	10% to 90% Rise Time
±1.5V	830ns
±2.5V	800ns
±5V	700ns

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1630/LT1631	Dual/Quad 30MHz, 10V/μs Rail-to-Rail Input and Output Op Amps	High DC Accuracy, 525µV V _{OS(MAX)} , 70mA Output Current, Max Supply Current 4.4mA per Amp
LT1638/LT1639	Dual/Ouad 1.2MHz, 0.4V/µs, Over-The-Top TM Micropower Rail-to-Rail Input and Output Op Amps	170µA Supply Current, Single Supply Input Range –0.4V to 44V, Rail-to-Rail Input and Output
LT1783	Micropower Over-The-Top SOT-23 Rail-to-Rail Input and Output Op Amp	SOT-23 Package, Micropower 220µA per Amplifier, Rail-to-Rail Input and Output, 1.2MHz Gain Bandwidth
LT1880	SOT-23 Rail-to-Rail Output, Picoamp Input Current Precision Op Amp	150μV Maximum Offset Voltage, 900pA Maximum Bias Current, 1.1MHz Gain Bandwidth, –40°C to 85°C Temperature Range

Over-The-Top is a trademark of Linear Technology Corporation.

